NSN 5961-01-285-6685

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-285-6685 **Inclosure Material:** Ceramic **Overall Length:** Between 0.150 inches and 0.175 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.068 inches and 0.076 inches **Mounting Method:** Terminal **Features Provided:** Electrostatic sensitive and gold plated leads **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 0.4 forward voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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